

In The Specification

Please replace the paragraph beginning on page 1, line 11 as shown below.

In a patent application filed on even day herewith under ~~attorney docket number S1022/7945~~ application serial number 08/968,598 and incorporated herein by reference, a method for fabricating a bipolar transistor compatible with a BICMOS technology (that is, a technology enabling the simultaneous fabrication of bipolar transistors and of complementary MOS transistors) is described.